Sea	arcn Notes

Application No.	Applicant(s)	
10/612,836	WEIMER ET AL.	
Examiner	Art Unit	
Stanban M. Smoot	2912	

SEARCHED				
Class	Subclass	Date	Examiner	
438	301	9/16/2004	sws	
438	303	9/16/2004	sws	
438	595	9/16/2004	sws	
438	786	9/16/2004	sws	
438	791	9/16/2004	sws	Jan.S.
427	255.29	9/16/2004	sws	] [
427	255.39	9/16/2004	sws	] [
427	255.393	9/16/2004	sws	
427	255.394	9/16/2004	sws	<u>J</u>
Updated	Above	12/16/2004	sws 🔏	12.2.
				,

INTERFERENCE SEARCHED				
Class	Subclass	Date	Examiner	
		,		
Same as Above		12/16/2004	S.W.S. sws	

SEARCH NOT (INCLUDING SEARCH		)
	DATE	EXMR
Key Words: Chemical Vapor Deposition - CVD, Tetrachlorosilane - TCS, Hexachlorodisilane - HCD;	9/16/2004	M.J. sws
Deuterated Silicon Nitride - Spacer; Deuterated Silicon Oxynitride;	9/16/2004	IW.J., sws
Anisotropic Etching - Gate Stack; Ion Implantation - Source/Drain Regions; DRAM.	9/17/2004	IN. sws
Updated Above Search	12/16/2004	S.W.S. sws
Search Tools - EAST (attached): USPAT; US PG PUBS; Derwent; EPO; JPO; IBM TDB	9/16/2004 12-16-04	sws Jn, J